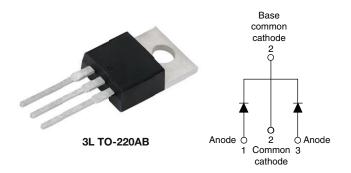
Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 30 A



www.vishay.com

| PRIMARY CHARACTERISTICS | | | | | |
|----------------------------------|-----------------|--|--|--|--|
| I _{F(AV)} | 2 x 30 A | | | | |
| V _R | 150 V | | | | |
| V _F at I _F | 0.72 V | | | | |
| I _{RM} max. | 20 mA at 125 °C | | | | |
| T _J max. | 175 °C | | | | |
| E _{AS} | 0.4 mJ | | | | |
| Package | 3L TO-220AB | | | | |
| Circuit configuration | Common cathode | | | | |

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation



HALOGEN

FREE

- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-60CTQ150... center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | |
|-----------------------------------|-----------------------------------------------------------------|-------------|----|--|--|--|--|
| SYMBOL | CHARACTERISTICS VALUES UNI | | | | | | |
| I _{F(AV)} | Rectangular waveform | 60 | А | | | | |
| V _{RRM} | | 150 | V | | | | |
| IFSM | $t_p = 5 \ \mu s \ sine$ | 710 | А | | | | |
| V _F | 30 A _{pk} , T _J = 125 °C (typical, per leg) | 0.69 | V | | | | |
| TJ | Range | -55 to +175 | °C | | | | |

| VOLTAGE RATINGS | | | | | | |
|--------------------------------------|------------------|----------------|-------|--|--|--|
| PARAMETER | SYMBOL | VS-60CTQ150-M3 | UNITS | | | |
| Maximum DC reverse voltage | VR | 150 | V | | | |
| Maximum working peak reverse voltage | V _{RWM} | 130 | V | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|-----------------------------------------|--------------------|-------------------------------------------------------------------|-------------------------------------------|-------|----|--|--|
| PARAMETER | SYMBOL | TEST CONDI | VALUES | UNITS | | | |
| Maximum average forward per leg | | 50 % duty avala at T ₂ = 137 °C | rectangular waveform | 30 | | | |
| current, see fig. 5 per device | I _{F(AV)} | 50 % duty cycle at T _C = 137 °C, rectangular waveform | | 60 | | | |
| Maximum peak one cycle non-repetitive | | 5 μs sine or 3 μs rect. pulse | Following any rated load condition and | 710 | A | | |
| surge current per leg, see fig. 7 | IFSM | 10 ms sine or 6 ms rect. pulse | with rated V _{RRM} applied | 270 | | | |
| Non-repetitive avalanche energy per leg | E _{AS} | T _J = 25 °C, I _{AS} = 0.9 A, L = 1 mH | | 0.4 | mJ | | |
| Repetitive avalanche current per leg | | Current decaying linearly to zer Frequency limited by T_J maxim | | 0.9 | А | | |

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| ELECTRICAL SPECIFICATIONS | | | | | | | | |
|----------------------------------------------------|--------------------------------|---------------------------------------------------------------|---------------------------------|------|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | TYP | MAX. | UNITS | | |
| | | 30 A | T ₁ = 25 °C | 0.83 | 0.88 | | | |
| Maximum forward voltage drop per leg See fig. 1 | V _{FM} ⁽¹⁾ | 60 A | 1j=25 0 | 0.98 | 1.09 | V | | |
| | VFM (** | 30 A | T 105 %O | 0.67 | 0.72 | | | |
| | | 60 A | T _J = 125 °C | 0.82 | 0.87 | | | |
| Maximum reverse leakage current per leg | | $T_J = 25 \ ^{\circ}C$ | $V_{\rm B}$ = Rated $V_{\rm B}$ | 7 | 75 | μA | | |
| See fig. 2 | I _{RM} | T _J = 125 °C | $v_{\rm R} = naleu v_{\rm R}$ | 7.2 | 20 | mA | | |
| Typical junction capacitance per leg | CT | $V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C | | - | 650 | pF | | |
| Typical series inductance per leg | L _S | Measured lead to lead 5 mm from package body | | | 7.5 | nH | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | | - | 10 000 | V/µs | | |

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,\,duty\,cycle$ < 2 $\,\%$

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|------------------------------------------------|-------------|-----------------------------------|--------------------------------------|-------------|------------|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum junction and storage temperature range | • | T _J , T _{Stg} | | - 55 to 175 | °C | |
| Maximum thermal resistance, | per leg | P | DC operation See fig. 4 | 1.2 | | |
| junction to case | per package | R _{thJC} | DC operation | 0.6 | °C/W | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased | 0.25 | 0,11 | |
| Approximate weight | | | | 6 | g | |
| Approximate weight | | | | 0.21 | oz. | |
| Mounting torque | minimum | | | 6 (5) | kgf · cm | |
| maximum | | | | 12 (10) | (lbf ⋅ in) | |
| Marking device | | | Case style 3 L TO-220AB | 60CT | Q150 | |



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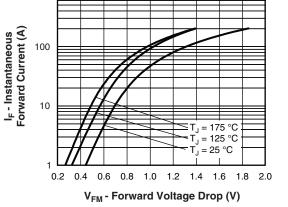


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

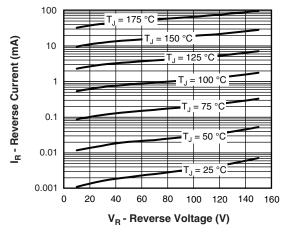


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

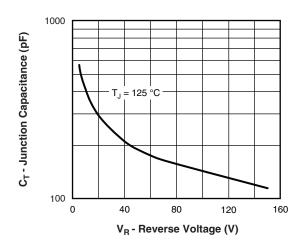


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

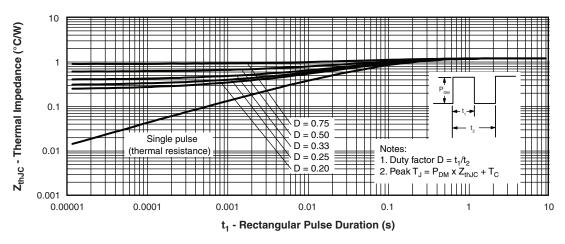
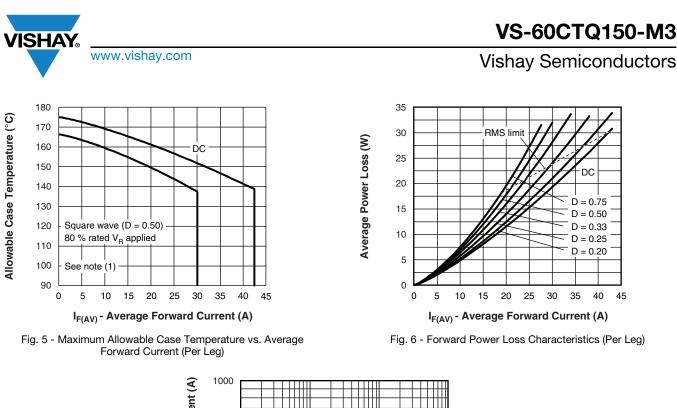


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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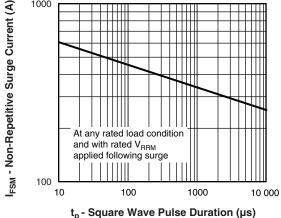


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

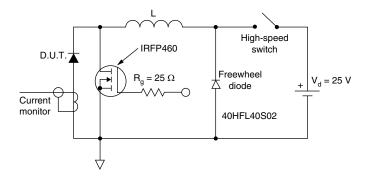


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);

 Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = 80 % rated V_R

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WISHAY www.vishay.com

ORDERING INFORMATION TABLE

| Device code | VS- | 60 | С | т | Q | 150 | -M3 |
|-------------|-----|---------|-----------|-----------|----------|----------|---------|
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 |
| 1 | - | Vishay | Semico | nductor | s produo | ct | |
| 2 | - | Curren | t rating | (60 = 60 | A) | | |
| 3 | - | Circuit | configui | ration | | | |
| | | C = co | mmon c | athode | | | |
| 4 | - | Packag | je | | | | |
| | | T = TO | -220 | | | | |
| 5 | - | Schott | ky "Q" se | eries | | | |
| 6 | - | Voltage | e rating | (150 = 1 | 50 V) | | |
| 7 | - | Enviro | nmental | digit | | | |
| | | -M3 = ł | nalogen | -free, Ro | HS-con | npliant, | and ter |

| ORDERING INFORMATION (Example) | | | | | | |
|-----------------------------------------------------------------------------|----|------|-------------------------|--|--|--|
| PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION | | | | | | |
| VS-60CTQ150-M3 | 50 | 1000 | Antistatic plastic tube | | | |

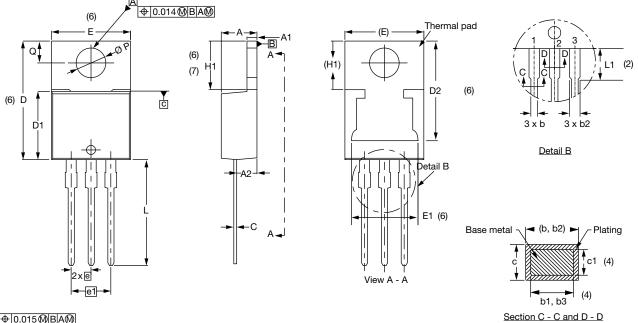
| LINKS TO RELATED DOCUMENTS | | | | | |
|-------------------------------------|--------------------------|--|--|--|--|
| Dimensions www.vishay.com/doc?96154 | | | | | |
| Part marking information | www.vishay.com/doc?95028 | | | | |



Vishay Semiconductors

3L TO-220AB

DIMENSIONS in millimeters and inches



⊕0.015@BA@





| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|---------|--------|--------|-------|-------|-------|
| STNIBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.25 | 4.65 | 0.167 | 0.183 | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | |
| A2 | 2.50 | 2.92 | 0.098 | 0.115 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.36 | 0.61 | 0.014 | 0.024 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 |
| D | 14.85 | 15.35 | 0.585 | 0.604 | 3 |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | |

| Conforms to JEDEC® | outline | TO-220AB |
|--------------------|---------|----------|
| | ouume | 10-220AD |

| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|--------|--------|--------|-------|-------|-------|
| STWBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D2 | 11.68 | 12.88 | 0.460 | 0.507 | 6 |
| Е | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |
| E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6, 7 |
| L | 13.52 | 14.02 | 0.532 | 0.552 | |
| L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| ØР | 3.54 | 3.91 | 0.139 | 0.154 | |
| Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| | | | | | |

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2 (minimum)

Revision: 03-Aug-17

 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Controlling dimensions: inches



Vishay

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